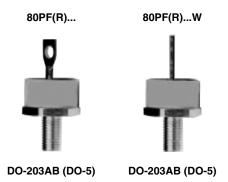
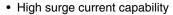


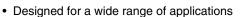
Vishay High Power Products

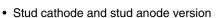
Standard Recovery Diodes, Generation 2 DO-5 (Stud Version), 80 A



FEATURES







- · Wire version available
- · Low thermal resistance
- · UL approval pending
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for multiple level

TYPICAL APPLICATIONS

Battery chargers

- Converters
- · Power supplies
- · Machine tool controls
- Welding

PRODUCT SUMMARY				
I _{F(AV)}	80 A			

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
I _{F(AV)}		80	А		
	T _C	140	°C		
I _{F(RMS)}		126	А		
I _{FSM}	50 Hz	1500	Λ.		
	60 Hz	1570	A		
I ² t	50 Hz	11 250	A ² s		
	60 Hz	10 230	A-5		
V _{RRM}	Range	400 to 1200	V		
T _J		- 55 to 180	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA	
	40	400	500		
80PF(R)(W)	80	800	960	9	
	120	1200	1440		

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80PF(R)...(W) Series

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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	180° conduction, half sine wave		80	А	
at case temperature	·F(AV)			140	°C	
Maximum RMS forward current	I _{F(RMS)}				126	Α
		t = 10 ms	No voltage	Sinusoidal half wave,	1500	А
Maximum peak, one-cycle forward, non-repetitive surge current	I _{FSM}	t = 8.3 ms	reapplied		1570	
		t = 10 ms	100 % V _{RRM}		1260	
		t = 8.3 ms	reapplied		1320	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage	initial T _J = 150 °C	11 250	A ² s
		t = 8.3 ms	reapplied		10 230	
		t = 10 ms	100 % V _{RRM}		7950	
		t = 8.3 ms	reapplied		7200	
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied		112 500	A ² √s	
Low level value of threshold voltage	V _{F(TO)}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		0.73	V	
Low level value of forward slope resistance	r _f	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		3.0	mΩ	
Maximum forward voltage drop	V_{FM}	$I_{pk} = 220 \text{ A}, T_J = 25 \text{ °C}, t_p = 400 \mu\text{s} \text{ rectangular wave}$ 1.40 V		V		

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		- 55 to 180	°C	
Maximum thermal resistance, junction to case	R _{thJC}	R _{thJC} DC operation		KAM	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25	K/W	
Maximum allowable mounting torque (+ 0 %, - 10 %)		Not lubricated thread, tighting on nut (1)	3.4 (30)		
		Lubricated thread, tighting on nut (1)	2.3 (20)	N⋅m	
		Not lubricated thread, tighting on hexagon (2)	4.2 (37)	(lbf · in)	
		Lubricated thread, tighting on hexagon (2)	3.2 (28)		
Approximate weight			15.8	g	
Approximate weight			0.56	OZ.	
Case style		See dimensions - link at the end of datasheet	eet DO-203AB (DO-5)		

Notes

⁽¹⁾ Recommended for pass-through holes

⁽²⁾ Torque must be appliable only to hexagon and not to plastic structure, recommended for holed heatsink



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△R _{thJC} CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.14	0.10			
120°	0.16	0.17			
90°	0.21	0.22	$T_J = T_J$ maximum	K/W	
60°	0.30	0.31			
30°	0.50	0.50			

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

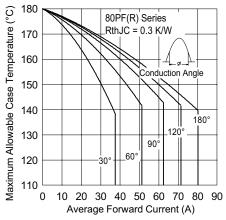


Fig. 1 - Current Ratings Characteristics

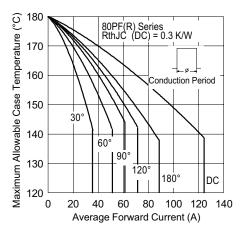


Fig. 2 - Current Ratings Characteristics

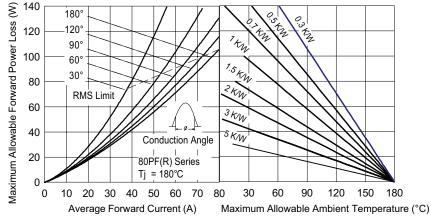


Fig. 3 - Forward Power Loss Characteristics

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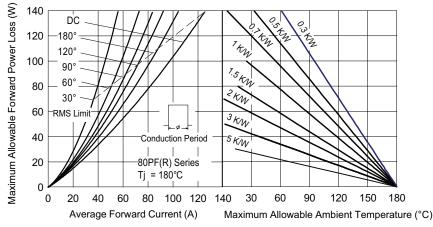
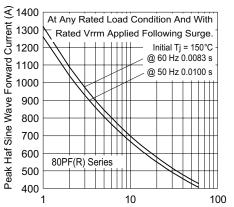


Fig. 4 - Forward Power Loss Characteristics



Number Of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

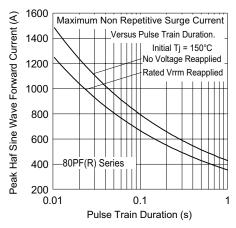


Fig. 6 - Maximum Non-Repetitive Surge Current

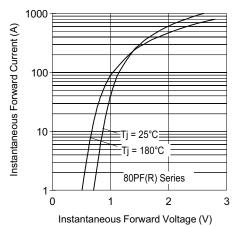


Fig. 7 - Forward Voltage Drop Characteristics

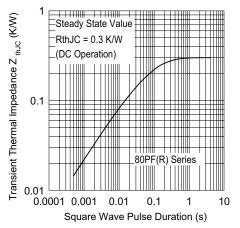


Fig. 8 - Thermal Impedance ZthJC Characteristics

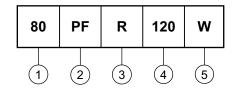


Standard Recovery Diodes, Generation 2 DO-5 (Stud Version), 80 A

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ORDERING INFORMATION TABLE

Device code



- 1 • 80 = Standard device
 - 82 = Isolated lead on standard terminal with silicone sleeve available for 1200 V only (red = Reverse polarity)
 (blue = Normal polarity)
- PF = Plastic package
- None = Stud normal polarity (cathode to stud)
 - R = Stud reverse polarity (anode to stud)
- Voltage code x 10 = V_{RRM} (see Voltage Ratings table)
- None = Standard terminal
 (see dimensions for 80PF(R)... link at the end of datasheet)
 - W = Wire terminal (see dimensions for 80PF(R)...W - link at the end of datasheet)

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95345		

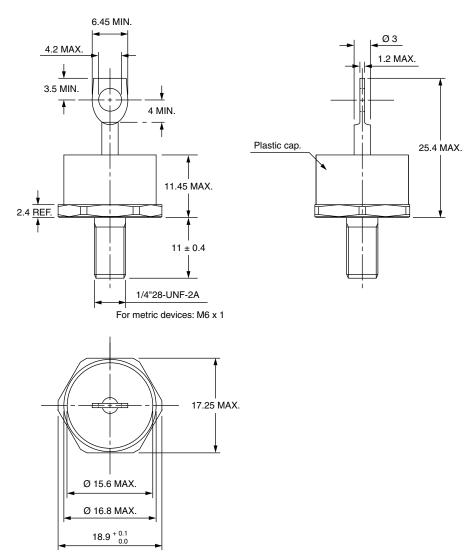
Document Number: 93526 Revision: 20-May-09



Vishay Semiconductors

DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W) and 95PF(R)...(W) Series

DIMENSIONS FOR 80PF(R), 50PF(R) AND 95PF(R) SERIES in millimeters



Note

• For metric device please contact factory

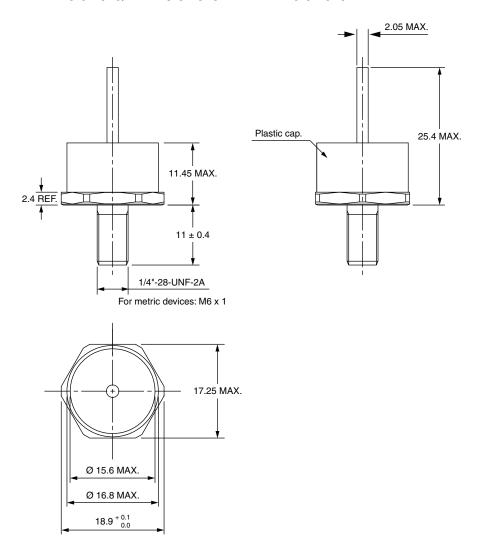
Outline Dimensions

Vishay Semiconductors

DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W) and 95PF(R)...(W) Series



DIMENSIONS FOR 80PF(R)...(W), 50PF(R)...(W) AND 95PF(R)...(W) SERIES in millimeters



Note

• For metric device please contact factory

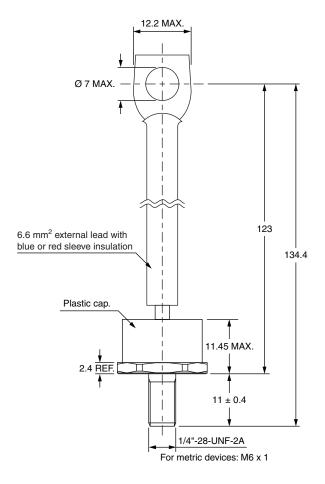
Document Number: 95345 Revision: 26-Aug-08



DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W) and 95PF(R)...(W) Series

Vishay Semiconductors

DIMENSIONS FOR 52PF(R), 82PF(R) AND 97PF(R) SERIES in millimeters



Note

• For metric device please contact factory



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